

PHD**D150A(K)1K8VB...SERIES****STANDARD RECOVERY DIODES****Stud Version****Features**

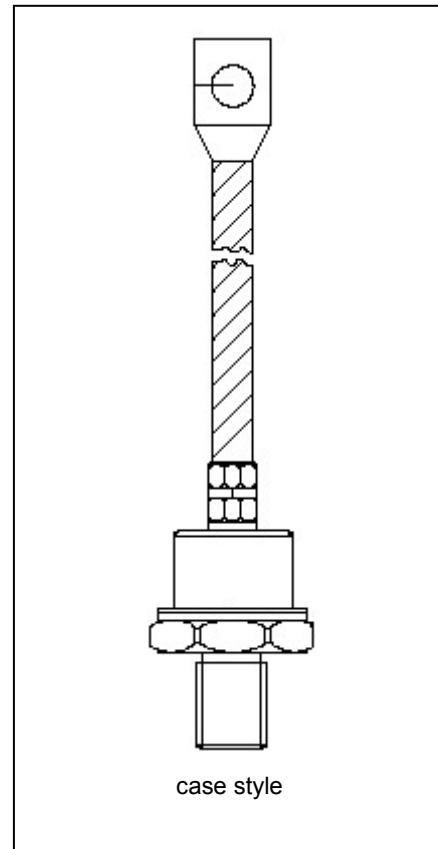
- Hermetic metal case with ceramic insulator
- High surge current capabilities
- Stud cathode and stud anode version

150A**Typical Applications**

- Converters
- Power supplies
- Machine tool controls
- High power drives
- Medium traction applications

Major Ratings and Characteristics

Parameters	D150A(K) 1K8VB	Units
$I_{F(AV)}$	150	A
@ T_{hs}	140	°C
$I_{F(RMS)}$	240	A
I_{FSM}	2000	A
@ 50Hz	2000	A
@ 60Hz	2090	A
$I^2 t$	20000	$A^2 s$
@ 50Hz	20000	$A^2 s$
@ 60Hz	18180	$A^2 s$
V_{RRM} range	1800	V
T_J	- 40 to 180	°C



PHD**D150A(K)1K8VB...SERIES****ELECTRICAL SPECIFICATIONS****Voltage Ratings**

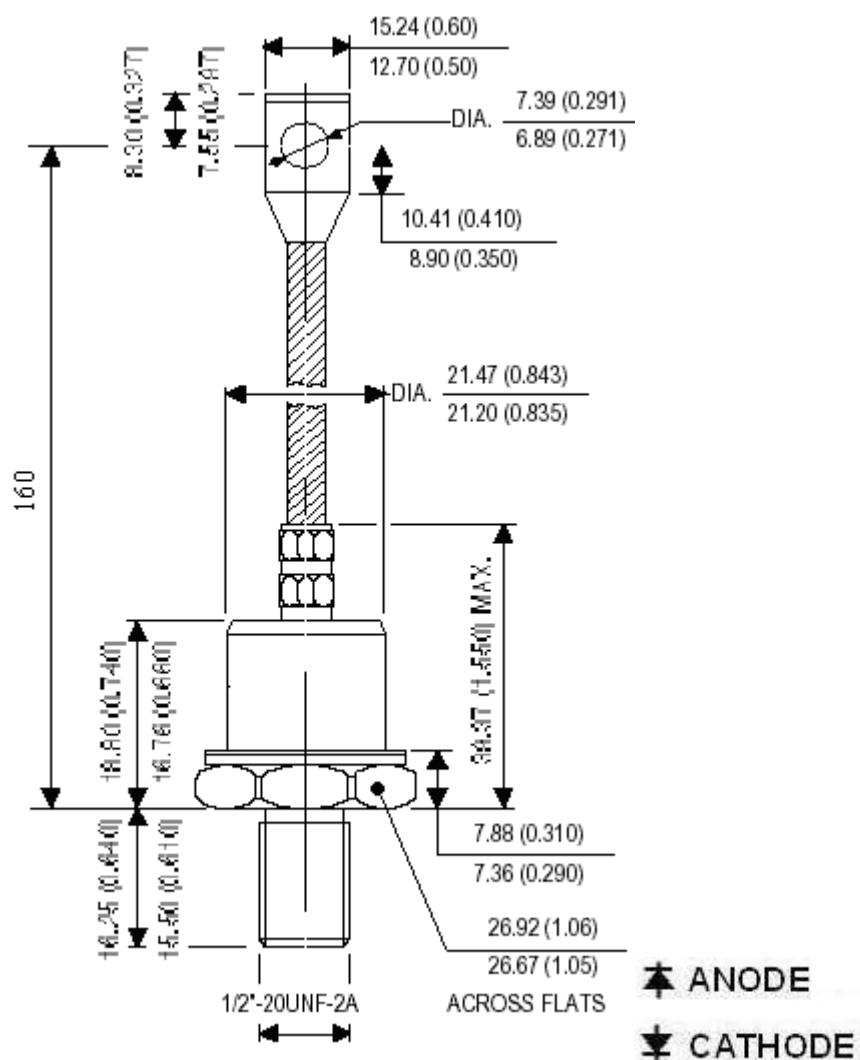
D150A(K)	Voltage Code	V_{RRM} , maximum repetitive peak reverse voltage V	V_{RSM} , maximum non-repetitive peak rev. voltage V	I_{RRM} max. @ $T_J = T_{J\max}$ mA
	04	400	500	9
	08	800	900	
	12	1200	1300	
	14	1400	1500	
	18	1800	1900	

Forward Conduction

Parameter	D150A(K)	Units	Conditions			
$I_{F(AV)}$ Max. average forward current @ Heatsink temperature	150	A	180° conduction, half sine wave Double side (single side) cooled			
	140	°C				
$I_{F(RMS)}$ Max.RMS forward current	240	A	DC@110°C case temperature			
I_{FSM} , Max. peak, one-cycle forward, non-repetitive surge current	2000	A	$t = 10ms$	No voltage reapplied	Sinusoidal half wave, Initial $T_J = 150^\circ C$	
	2090		$t = 8.3ms$	100% V_{RRM} reapplied		
	1680		$t = 10ms$			
	1760		$t = 8.3ms$	100% V_{RRM} reapplied		
$I^2 t$ Maximum $I^2 t$ for fusing	20000	$A^2 s$	$t = 10ms$	No voltage reapplied	Initial $T_J = 150^\circ C$	
	18180		$t = 8.3ms$	100% V_{RRM} reapplied		
	14100		$t = 10ms$			
	12800		$t = 8.3ms$	100% V_{RRM} reapplied		
$I^2 \sqrt{t}$ Maximum $I^2 \sqrt{t}$ for fusing	200000	$A^2 \sqrt{s}$	$t = 0.1$ to $10ms$, no voltage reapplied			
V_{TM} Max. forward voltage drop	1.40	V	$I_{pk} = 267A$, $T_J = 25^\circ C$, $t_p=400 \mu s$ rectangular wave			
$V_{F(TO)}$ Low level value of threshold voltage	0.73	V	$(16.7\% \times \pi \times I_{F(AV)} < 1 < \pi \times I_{F(AV)})$, $T_J=T_{J\max}$			
r_f Low level value of forward slope resistance	0.49	MΩ	$(16.7\% \times \pi \times I_{F(AV)} < 1 < \pi \times I_{F(AV)})$, $T_J=T_{J\max}$			

Thermal and Mechanical Specification

Parameter	D150A(K)	Units	Conditions	
T_J Max.junction operating temperature range	-55 to 180	°C		
T_{stg} Max. storage temperature range	-55 to 180			
R_{thJC} Max.thermal resistance,junction to case	0.27	K/W	DC operation	
R_{thCS} Max. thermal resistance,Case to heatsink	0.25		DC operation single(double) side cooled	
T Max.allowed Mounting torque, ± 10%	7	N		
wt Approximate weight	115	g		



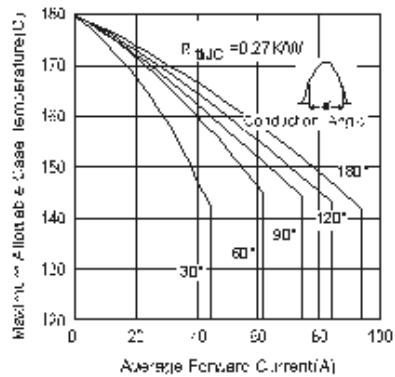


Fig.1-Current Ratings Characteristics

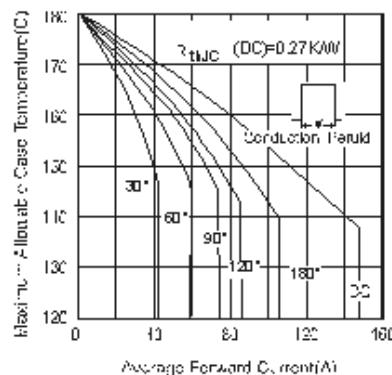


Fig.2-Current Ratings Characteristics

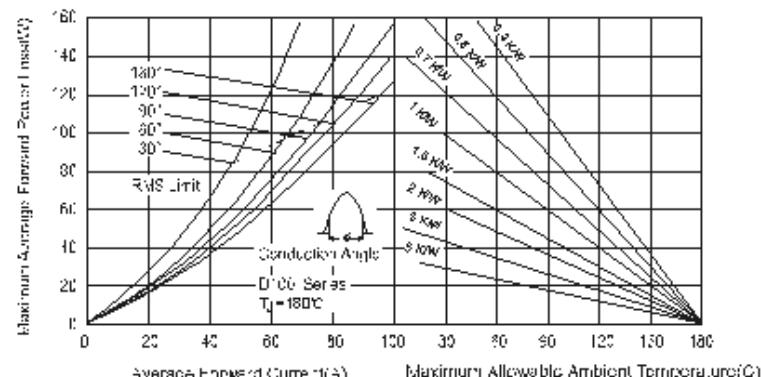


Fig.3-Forward Power Loss Characteristics

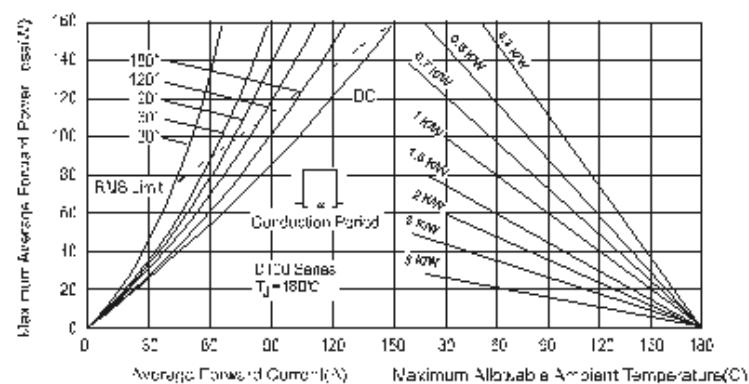


Fig.4-Forward Power Loss Characteristics